Technical Data *Green Products*
Data Sheet N0824, Rev. A

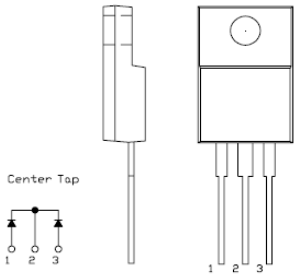
MBRF1080CTP SCHOTTKY RECTIFIER

Applications:

- **Switching power supply**
- **Converters**
- **Free-Wheeling diodes**
- **Reverse battery protection**

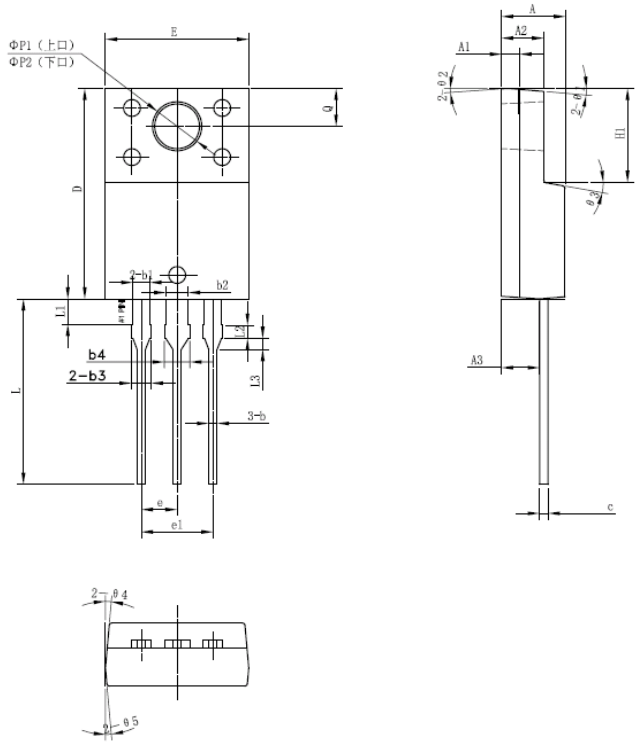
Features:

- **125°C T_J operation**
- **Center tap configuration**
- **Low forward voltage drop**
- **High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance**
- **High frequency operation**
- **Guard ring for enhanced ruggedness and long term reliability**
- **Terminals: pure tin plated, solderable per MIL-STD-750, Method 2026**
- **This is a Pb − Free Device**
- **All SMC parts are traceable to the wafer lot**
- **Additional testing can be offered upon request**



OUTLINE DRAWING

Mechanical Dimensions (In mm):



SYMBOL	MIN.	TYP.	MAX.
A	4.30	4.50	4.70
A1	1.10	1.30	1.50
A2	2.80	3.00	3.20
A3	2.50	2.70	2.90
b	0.50	0.60	0.75
b1	1.10	1.20	1.35
b2	1.50	1.60	1.75
b3	1.20	1.30	1.45
b4	1.60	1.70	1.85
c	0.55	0.60	0.75
D	14.80	15.00	15.20
E	9.96	10.16	10.36
e		2.55	
e1		5.10	
H1	6.50	6.70	6.90
L	12.70	13.20	13.70
L1	1.60	1.80	2.00
L2	0.80	1.00	1.20
L3	0.60	0.80	1.00
ΦP1(上口)	3.30	3.50	3.70
ΦP2(下口)	2.99	3.19	3.39
Q	2.50	2.70	2.90
Θ1		5°	
Θ2		4°	
Θ3		10°	
Θ4		5°	
Θ5		5°	

ITO-220AB

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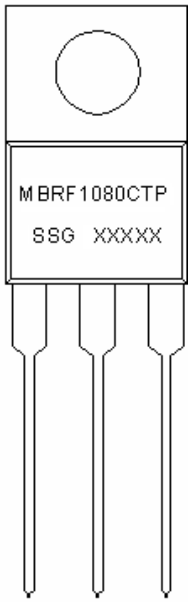
Marking Diagram:



Where XXXXX is YYWWL

MBR = Device Type
F = Package type
10 = Forward Current (10A)
80 = Reverse Voltage (80V)
CTP = Configuration
SSG = SSG
YY = Year
WW = Week
L = Lot Number

Cautions: Molding resin
Epoxy resin UL:94V-0

Ordering Information:

Device	Package	Shipping
MBRF1080CTP	ITO-220AB (Pb-Free)	50pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	-	80	V
Average Rectified Forward Current	$I_{F(AV)}$	50% duty cycle @T_C =105°C, rectangular wave form	5(Per leg) 10(Per device)	A
Peak One Cycle Non-Repetitive Surge Current (per leg)	I_{FSM}	8.3 ms, half Sine pulse	125	A

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Electrical Characteristics:

Characteristics	Symbol	Condition	Typ.	Max.	Units
Forward Voltage Drop (per leg)*	V_{F1}	@ 5A, Pulse, T_J = 25 °C	0.67	0.69	V
	V_{F2}	@ 5A, Pulse, T_J = 125 °C	0.59	0.64	V
Reverse Current at DC condition (per leg)*	I_{R1}	@V_R = rated V_R T_J = 25 °C	0.06	1.0	mA
Reverse Current (per leg)*	I_{R2}	@V_R = rated V_R T_J = 125 °C	11	30	mA
Junction Capacitance (per leg)	C_T	@V_R = 5V, T_C = 25 °C f_{SIG} = 1MHz	120	220	pF
Series Inductance (per leg)	L_S	Measured lead to lead 5 mm from package body	8.0	-	nH
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

* Pulse Width < 300μs, Duty Cycle <2%

Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	T_J	-	-55 to +125	°C
Storage Temperature	T_{stg}	-	-55 to +125	°C
Typical Thermal Resistance Junction to Case (per leg)	$R_{\theta JC}$	DC operation	3.5	°C/W
Approximate Weight	wt	-	2	g
Case Style	ITO-220AB			

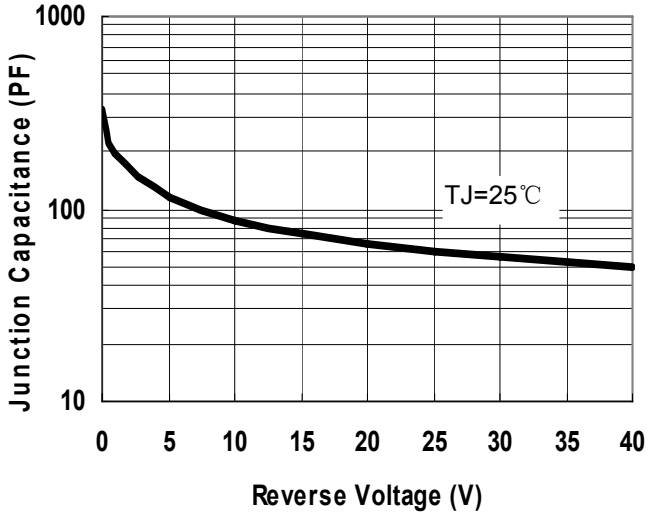

Fig.1-Typical Junction Capacitance

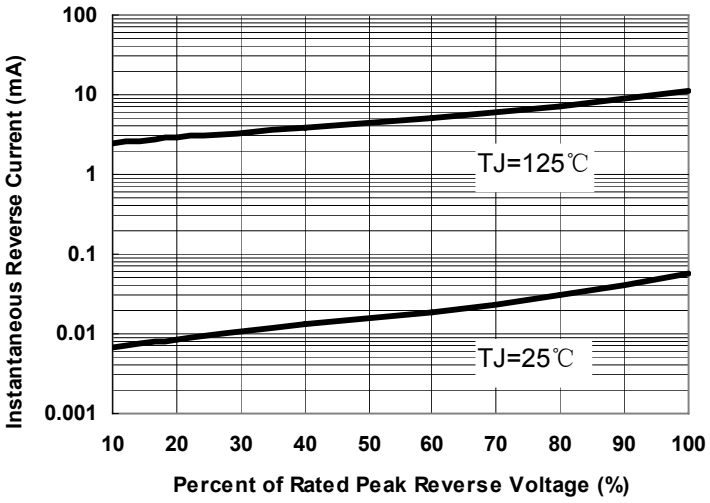

Fig.2-Typical Reverse Characteristics

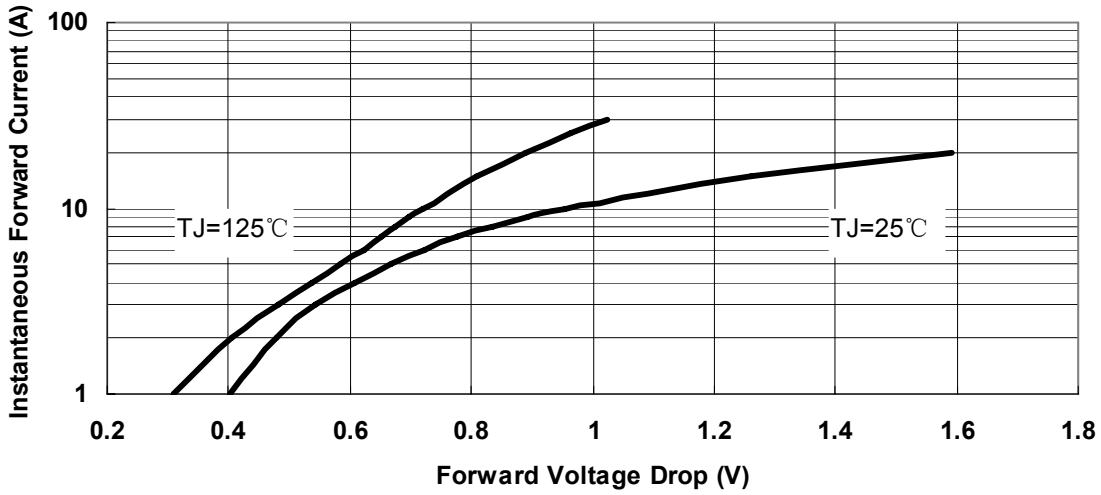

Fig.3-Typical Instantaneous Forward Voltage Characteristics

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